

Features

- Current:5-300A,Voltage:100-1600V
- All models feature the same compact dimensions to Provide auniform mounting pitch
- Glass passivated diode chip
- Excellent power/volume ratio,High thermal conductivity Package, electrically insulated case

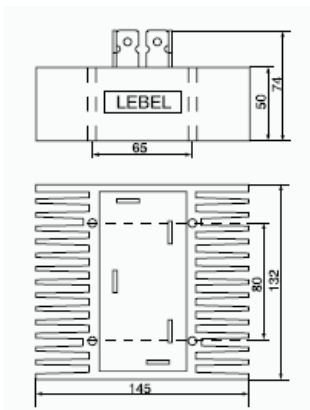
$I_{F(AV)}$	150-300A
V_{RRM}	100-1600V
V_F	1.1V
I_{FSM}	400A

Typical Applications

- Eliminator supply,industrial automatic control
- Numierial-controlled machinery,telecontrol system

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	VALUE		UNIT
			Min	Max	
$I_{F(AV)}$	Mean forward current	180 ° sine wave, 50HZ Double side cooled, THS=55°C	150	300	A
V_{RRM}	Repetitive peak reverse voltage	$V_{DRM}\&V_{RRM}$ tp=10ms $V_{DSM}\&V_{RSM}=V_{DRM}\&V_{RRM}+100V$	100	1600	V
V_{RMS}	RMS current		70	860	V
V_{DC}	DC blocking voltage		100	1600	V
I_{FSM}	Surge on-state current	sine wave		400	A
V_F	Diode forward voltage	$I_F=17.5A$		1.1	V
I_R	Reverse leakage current	$T_a=25^\circ C$		10	uA
$I_{R(H)}$		$T_a=100^\circ C$		200	uA
$R_{th(j-c)}$	Thermal impedance node to the shell	180 ° sine wave, single heat sink		5.0	°C/W
$R_{th(c-a)}$	Thermal impedance (shell to powder)	180 ° sine wave, single heat sink		8	°C/W
V_{iso}	Insulation voltage		2500		V
T_J	Stored temperature		-40	125	°C
T_{stq}	Stored temperature		-40	150	°C
W_t	Weight			1200	g
Outline					

Outline:



Circuit Drawing:

